# 10V Drive Nch MOSFET

# **R5021ANX**

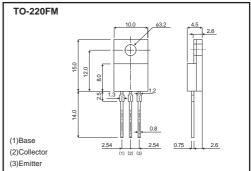
#### Structure

Silicon N-channel MOSFET

#### Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Gate-source voltage (VGSS) guaranteed to be  $\pm 30$ V.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.

# ●Dimensions (Unit:mm)



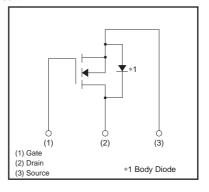
#### Applications

Switching

#### Packaging specifications

	Package	Bulk
Туре	Code	_
	Basic ordering unit (pieces)	500
R5021	0	

# •Inner circuit



#### ● Absolute maximum ratings (Ta=25°C)

Parameter	Symbo	ı	Limits	Unit	
Drain-source voltage	VDSS		500	V	
Gate-source voltage	Vgss		±30	V	
Drain current	Continuous	ΙD	*3	±21	А
	Pulsed	IDP	*1	±84	А
Source current	Continuous	ls	*3	21	А
(Body Diode)	Pulsed	Isp	*1	84	А
Avalanche Current	las	*2	10.5	А	
Avalanche Energy	Eas	*2	29.6	mJ	
Total power dissipation	Po		50	W	
Channel temperature	Tch		150	°C	
Range of storage tem	Tstg		-55 to +150	°C	

<sup>\*1</sup> Pw≤10 $\mu$ s, Duty cycle≤1% \*2 L $\stackrel{.}{=}$  500 $\mu$ H, V $_{DD}$ =50V, Rg=25 $\Omega$ , Starting, Tch=25°C \*3 Limited only by maximum temperature allowed

#### Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to case	Rth(ch-c)	2.5	°C/W

#### ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Gate-source leakage	Igss	_	_	±100	nA	Vgs=±30V, Vps=0V	
Drain-source breakdown voltage	V(BR)DSS	500	_	_	V	In=1mA, Vgs=0V	
Zero gate voltage drain current	Ipss	_	_	100	μΑ	VDS=500V, VGS=0V	
Gate threshold voltage	VGS(th)	2.5	_	4.5	V	VDS=10V, ID=1mA	
Static drain-source on-state resistance	RDS(on)*	_	0.16	0.21	Ω	ID=10.5A, VGS=10V	
Forward transfer admittance	Yfs   *	7	_	_	S	ID=10.5A, VDS=10V	
Input capacitance	Ciss	_	2300	_	pF	VDS=25V	
Output capacitance	Coss	_	1000	_	pF	Vgs=0V	
Reverse transfer capacitance	Crss	-	70	_	pF	f=1MHz	
Turn-on delay time	td(on) *	-	47	_	ns	ID=10.5A, VDD≒250V	
Rise time	tr *	_	70	_	ns	Vgs=10V	
Turn-off delay time	td(off) *	_	200	_	ns	RL=23.8Ω	
Fall time	t <sub>f</sub> *	_	70	_	ns	R <sub>G</sub> =10Ω	
Total gate charge	Qg *	_	64	_	nC	V <sub>DD</sub> ≒250V	
Gate-source charge	Qgs *		11	_	nC	I <sub>D</sub> =21A   V <sub>G</sub> s=10V	
Gate-drain charge	Q <sub>gd</sub> *	-	27	_	nC	R <sub>L</sub> =11.9Ω / R <sub>G</sub> =10Ω	

<sup>\*</sup> Pulsed

# ●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp*	_	-	1.5	V	Is= 21A, Vgs=0V

<sup>\*</sup> Pulsed

#### Electrical characteristic curves

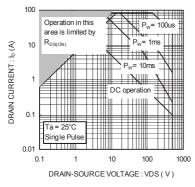


Fig.1 Maximum Safe Operating Aera

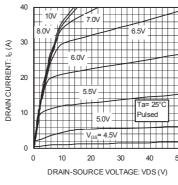


Fig.2: Typical Output Characteristics(  ${\tt I}$  )

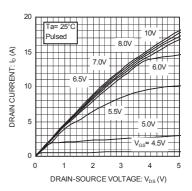


Fig.3: Typical Output Characteristics(  ${\rm 1\!I}$  )

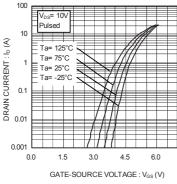


Fig.4 Typical Transfer Characteristics

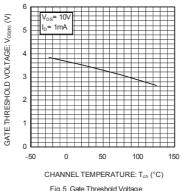


Fig.5 Gate Threshold Voltage vs. Channel Temperature

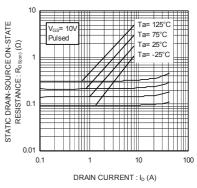
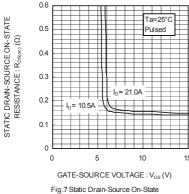


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current



Resistance vs. Gate Source Voltage

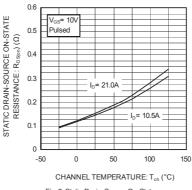


Fig.8 Static Drain-Source On-State Resistance vs. Channel Temperature

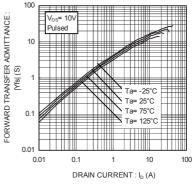
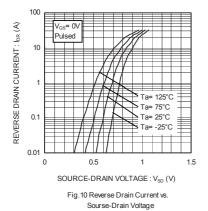
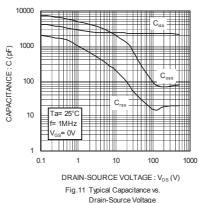
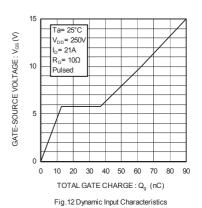
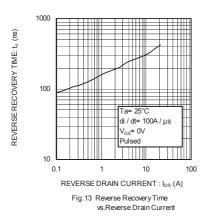


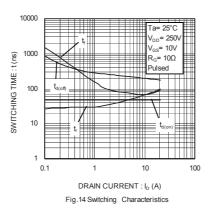
Fig.9 Forward Transfer Admittance vs. Drain Current











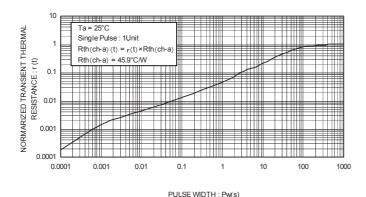


Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width

### Switching characteristics measurement circuit

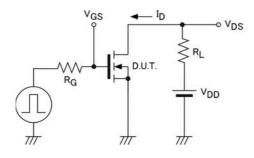


Fig.1-1 Switching Time Measurement Circuit

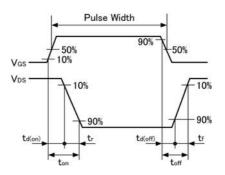


Fig.1-2 Switching Waveforms

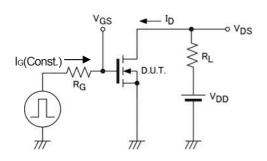


Fig.2-1 Gate Charge Measurement Circuit

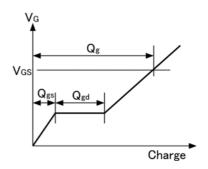


Fig.2-2 Gate Charge Waveform

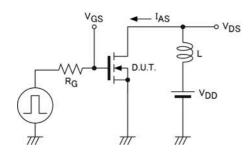


Fig.3-1 Avalanche Measurement Circuit

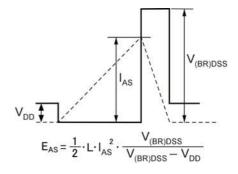


Fig.3-2 Avalanche Waveform

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